

(Use several sheets if necessary)

Application Number
09/534,503

Applicant(s)
Koji Tanizawa

Filing Date	March 24, 2000
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Group Art Unit

TO BE ASSIGNED

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

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OTHER DOCUMENTS *(Including Author, Title, Date, Pertinent Pages, Etc.)*

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INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)	ATTY DOCKET NO. AOY.003	SERIAL NO. 09/534,503
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U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
BWB	A	5,146,465	09/08/1992	KHAN et al.			
	B	5,565,832	08/12/1997	OHBA et al.			
	C	5,679,965	10/21/1997	SCHETZINA			
	D	5,932,896	08/03/1999	SUGIURA et al.			
BWB	E	5,959,307	09/28/1999	NAKAMURA et al.			

FOREIGN PATENT DOCUMENTS								
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
	F	11031841	02/02/1999	JAPAN	CITED IN IDS #2		✓	
	G	11068155	03/09/1999	JAPAN	//		✓	
BWB	H	06151966A	05/31/1994	JAPAN			✓	
I	I	07249795A	09/26/1995	JAPAN			✓	
J	J	08051251A	02/20/1996	JAPAN			✓	

OTHER DOCUMENTS			(Including Author, Title, Date, Pertinent Pages, Etc.)
BWB	K		Shuji Nakamura et al., "Present Status of InGa _N /Ga _N /AlGa _N -Based Laser Diodes" Jpn. J. Appl. Phys. Vol. 36 (1997) pp. L1568-L1571, Part 2, No. 12A, 1 December 1997
BWB	L		Shuji Nakamura et al., "InGa _N /Ga _N /AlGa _N -Based Laser Diodes with Modulation-Doped Strained-Layer Superlattices" Jpn. J. Appl. Phys. Vol. 36 (1997) ppl. L1568-L1571 Part 2, No. 12A, 1 December 1997

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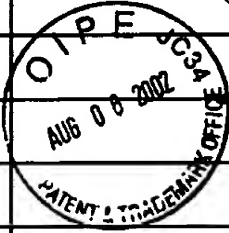
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		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
BWB	M	08097468A	04/12/1996	JAPAN			✓	
	N	08228025A	09/03/1996	JAPAN			✓	
	O	08330629A	12/13/1996	JAPAN			✓	
	P	09298341A	11/18/1997	JAPAN			✓	
BWB	Q	09232629A	09/05/1997	JAPAN			✓	

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BWB	R	Shuji Nakamura et al., "InxGa(1-x)N/InyGa(1-7)N superlattices grown on GaN films" J. Appl. Phys., Vol. 74, No. 6, 15 September 1993, pp. 3911-3915.

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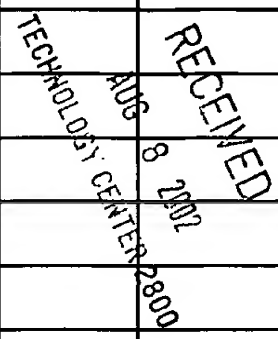
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	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
BWBs	10135514A	05/22/1998	JAPAN			✓	

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